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SPECIFICATION FOR

OPEN MODE GREEN TYPE MEDIUM VOLTAGE CAPACITORS

Series: OP Series

Description: Open Mode, 0805 to 1812 Size, X7R, 100V~500V,

ROHS Compliant

<u>DRAWN BY</u>	CHECKED BY	APPROVED BY
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1. INTRODUCTION

HITANO open-mode series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords open-mode pattern to prevent circuit leakage when focused to failure in a board flex situation.

2. FEATURES

- a. High voltage in a given case size.
- b. Circuit open during product cracking.
- c. High stability and reliability.

3. APPLICATIONS

- a. High current applications.
- b. Power supply and related industries
- c. The other mechanical stress concerned products.

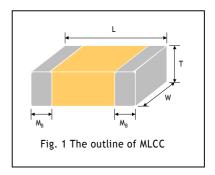
4. HOW TO ORDER

OP	0805	N	100	J	202	L	T
<u>Series</u>	<u>Size</u>	<u>Dielectric</u>	<u>Capacitance</u>	<u>Tolerance</u>	<u>Rated voltage</u>	<u>Termination</u>	<u>Packaging</u>
OP=Open-mode	0805 (2012) 1206 (3216) 1210 (3225) 1812 (4532)		.	K=±10% M=±20%	Iwo significant digits followed	L=Ag/Ni/Sn C=Cu/Ni/Sn (Note 1)	T=7" reeled G=13" reeled

Note 1: Please see below product range to find right termination code.

5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	T (mm)	Remark	M _B (mm)		
0805 (2012)	2.00±0.15	1.25±0.10	0.80±0.10	В	0.40±0.20		
0003 (2012)	2.0010.13	1.23±0.10	1.25±0.10	D	0.4010.20		
			0.80±0.10	В			
1206 (3216)	3.20±0.15	1.60±0.15	0.95±0.10	С	0.50±0.20		
1200 (3210)			1.25±0.10	D	0.30±0.20		
	3.20±0.20	1.60±0.20	1.60±0.20	G			
	3.20±0.30	2.50±0.20	0.95±0.10	С			
1210 (3225)	3.20±0.30	2.30±0.20	1.25±0.10	D			
	3.20±0.40	2.50±0.30	1.60±0.20	G	0.50±0.25		
	3.20±0.40	2.50±0.30	2.50 ± 0.30	М			
1812 (4532)	4.50±0.40	3.20±0.30	1.25±0.10	D	0.60±0.25		
1012 (4332)	2 (4532) 4.50±0.40		(4532) 4.50±0.40 3.20±0.30		2.00±0.20	К	0.00±0.25



6. GENERAL ELECTRICAL DATA

Dielectric	X7R
Size	0805, 1206, 1210, 1812
Capacitance*	100pF to 1μF
Capacitance tolerance	K (±10%), M (±20%)
Rated voltage (WVDC)	100V, 200V, 250V, 500V
Tan δ*	≤2.5%
Insulation resistance at Ur	≥10GΩ or RxC≥500Ω-F whichever is smaller
	100V: ≥2.5 x WVDC
Dielectric strength	200V and 250V: ≥2 x WVDC
	500V: ≥1.5 x WVDC
Operating temperature	-55 to +125°C
Capacitance characteristic	±15%
Termination	Ni/Sn (lead-free termination)

^{*} Measured at 25°C ambient temperature and 30-70% related humidity. Apply 1.0±0.2Vrms, 1.0kHz±10%.

[#] Reflow soldering only is recommended.

7. CAPACITANCE RANGE

DIELECTRIC								X	7R							
SIZE		0805 120				1210					1812					
RATED VOLTAGE (VDC)	100	200	250	500	100	200	250	500	100	200	250	500	100	200	250	500
100pF (101)		В	В	В												
120pF (121)		В	В	В												
150pF (151)		В	В	В	В	D	D	D								
180pF (181)		В	В	В	В	D	D	D								
220pF (221)		В	В	В	В	D	D	D								
270pF (271)		В	В	В	В	D	D	D								
330pF (331)		В	В	В	В	D	D	D								
390pF (391) 470pF (471)		В	В	B B	В	D	D	D D								
560pF (561)	B B	B B	B B	В	B B	D D	D D	D								
680pF (681)	В	В	В	В	В	D	D	D								
820pF (821)		В	В	В	В	D	D	D								
1,000pF (102)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
1,200pF (122)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
1,500pF (152)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
1,800pF (182)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
2,200pF (222)	В	В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
2,700pF (272)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
3,300pF (332)		В	В	В	В	D	D	D	С	С	С	С	D	D	D	D
3,900pF (392)	В	В	В		В	D	D	D	С	С	С	С	D	D	D	D
4,700pF (472)	В	В	В		В	D	D	D	С	С	С	С	D	D	D	D
5,600pF (562)	В	D	D		В	D	D	D	С	С	С	С	D	D	D	D
6,800pF (682)	В	D	D		В	D	D	D	С	С	С	С	D	D	D	D
8,200pF (822)	В	D	D		В	D	D	D	С	С	С	С	D	D	D	D
0.010µF (103)	В	D	D		В	D	D	D	С	С	С	С	D	D	D	D
0.012μF (123)		D	D		В	D	D	D	С	С	С	С	D	D	D	D
0.015μF (153)		D	D		В	D	D	D	С	С	С	С	D	D	D	D
0.018μF (183)		D	D		В	D	D	D	С	С	С	С	D	D	D	D
0.022μF (223)		D	D		В	D	D	G	С	С	С	D	D	D	D	D
0.027μF (273)	D				В	D	D	G	С	С	С	G	D	D	D	D
0.033µF (333)					В	G	G	G	С	С	С	G	D	D	D	D
0.039μF (393)					В	G	G		С	С	С	G	D	D	D	D
0.047μF (473)	D				В	G	G		С	D	D	G	D	D	D	D
0.056µF (563)					B B	G G	G G		C	D G	D G	G	D D	D D	D D	K K
0.068μF (683) 0.082μF (823)					В	G	G		C	G	G		D	D D	D	K
0.082μF (823) 0.10μF (104)					D	G	G		C	G	G		D	D	D	K
0.10μF (104) 0.12μF (124)					D	G	G		C	G	G		D	D	D	N.
0.12μF (124)					G				D	M	M		D	K	K	
0.18µF (184)					G				D	M	M		D	K	K	
0.22µF (224)					G				D	M	M		D	K	K	
0.27μF (274)									G	141	141		D	K	K	
0.33µF (334)									G				D	K	K	
0.39μF (394)									М				D	K	K	
0.47μF (474)									М				K	K	K	
0.56µF (564)									М				K			
0.68µF (684)													K			
0.82µF (824)													K			
1.0µF (105)													K			

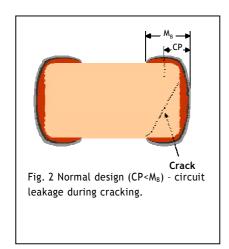
^{1.} The cell with red color mark is expressed product with Ag/Ni/Sn terminations.

8. PACKAGING DIMENSION AND QUANTITY

Size	Thickness (mm)	Pape	r tape	Plastic tape			
Size	Tilless (IIIII)	7" reel	13" reel	7" reel	13" reel		
0805	0.80±0.10	4k	15k	-	-		
0003	1.25±0.10	-	-	3k	10k		
	0.80±0.10	4k	15k	=	-		
1206	0.95±0.10	-	-	3k	10k		
1200	1.25±0.10	=	-	3k	10k		
	1.60±0.20	-	-	2k	-		
	0.95±0.10	=	-	3k	10k		
1210	1.25±0.10	-	-	3k	10k		
	1.60±0.20	=	-	2k	-		
	2.50 ± 0.30			1k			
1812	1.25±0.10	-	-	1k	-		
1012	2.00±0.20	-	-	1k	-		

Unit: pieces

9. INNER CONSTRUCTION OF OPEN-MODE DESIGN



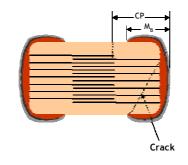


Fig. 3 Open-mode design (CP> M_B) - circuit open during cracking.

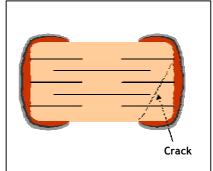


Fig. 4 Floating design (one kind of open-mode design)- circuit open during cracking.

10. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Condition	Requirements
1.	Visual and		* No remarkable defect.
	Mechanical		* Dimensions to conform to individual specification sheet.
2.	Capacitance	1.0±0.2Vrms, 1kHz±10%	* Shall not exceed the limits given in the detailed spec.
3.	Q/ D.F.		X7R: D.F. ≤2.5%
	(Dissipation		
	Factor)		
4.	Dielectric	* To apply voltage (≤50V) 250%.	* No evidence of damage or flash over during test.
	Strength	* Duration: 1 to 5 sec.	
		* Charge and discharge current less than 50mA.	
		* To apply voltage:	
		100V ≥3 times VDC	
		200V~300V ≥2 times VDC	
		500V ≥1.5 times VDC	
		* Cut-off, set at 10mA	
		* TEST= 15 sec.	
5.	Insulation	* RAMP=0	≥10GΩ or RxC≥100Ω-F whichever is smaller.
<i>J</i> .	Resistance	To apply rated voltage for 60 sec.	12-10-032 OF RACETOOM WITCHEVER IS SHIRAKET.
6.	Temperature	With no electrical load.	Within ±15%.
	Coefficient	Operating temperature: -55-125°C at 25°C	
7.	Adhesive	* Pressurizing force :	* No remarkable damage or removal of the terminations.
	Strength of	5N (≤0603) and 10N (>0603)	
8.	Termination Vibration	* Test time: 10±1 sec.	* No remarkable damage
٥.	Resistance	* Vibration frequency: 10-55 Hz/min. * Total amplitude: 1.5mm	* No remarkable damage. * Cap change and Q/D.F.: To meet initial spec.
	Resistance	* Test time: 6 hrs. (Two hrs each in three mutually	Cap Change and Q/D.I to meet initial spec.
		perpendicular directions.)	
9.	Solderability	* Solder temperature: 235±5°C	95% min. coverage of all metalized area.
		* Dipping time: 2±0.5 sec.	
10.	Bending Test	* The middle part of substrate shall be pressurized by means	* No remarkable damage.
		of the pressurizing rod at a rate of about 1 mm per second	* Cap change: X7R: within ±12.5%
		until the deflection becomes 1 mm and then the pressure	(This capacitance change means the change of capacitance under
		shall be maintained for 5±1 sec.	specified flexure of substrate from the capacitance measured
		* Measurement to be made after keeping at room temp. for 24±2 hrs.	before the test.)
11.	Resistance to	* Solder temperature: 270±5°C	* No remarkable damage.
	Soldering Heat	* Dipping time: 10±1 sec	* Cap change: X7R: within ±7.5%
	3	* Preheating: 120 to 150°C for 1 minute before immerse the	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		capacitor in a eutectic solder.	* 25% max. leaching on each edge.
		* Before initial measurement (Class II only): Perform	
		150+0/-10°C for 1 hr and then set for 48±4 hrs at room	
		temp.	
		* Measurement to be made after keeping at room temp. for	
12	Temperature	48±4 hrs.	* No remarkable damage
12.	Cycle	* Conduct the five cycles according to the temperatures and time.	* No remarkable damage. * Cap change: X7R: within ±7.5%
	Cycle	Step Temp. (°C) Time (min.)	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		1 Min. operating temp. +0/-3 30±3	
		2 Room temp. 2-3	
		3 Max. operating temp. +3/-0 30±3	
		4 Room temp. 2-3	
		* Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 48±4 hrs at room	
		temp.	
		* Measurement to be made after keeping at room temp. for	
		48±4 hrs.	
	<u> </u>	ı	

No.	Item	Test Condition	Requirements
13.	Humidity	* Test temp.: 40±2°C	* No remarkable damage.
	(Damp Heat)	* Humidity: 90~95% RH	* Cap change: X7R: within ±12.5%
	Steady State	* Test time: 500+24/-0hrs.	* Q/D.F. value: X7R: D.F. ≤3.0%
		* Measurement to be made after keeping at room temp. for 48±4 hrs. (Class II).	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
14.	Humidity	* Test temp.: 40±2°C	* No remarkable damage.
	(Damp Heat)	* Humidity: 90-95%RH	* Cap change: X7R: within ±12.5%
	Load	* Test time: 500+24/-0 hrs.	* Q/D.F. value: X7R: D.F. ≤3.0%
		* To apply voltage : rated voltage.	* I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.
		* Measurement to be made after keeping at room temp. for	
		48±4 hrs.	
15.	High	* Test temp.: X7R: 125±3°C	* No remarkable damage.
	Temperature	* To apply voltage:	* Cap change: X7R: within ±12.5%
	Load	(1) V<500V: 200% of rated voltage.	* Q/D.F. value: X7R: D.F. ≤3.0%
	(Endurance)	(2) 500V: 150% of rated voltage.	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
		* Test time: 1000+24/-0 hrs.	
		* Measurement to be made after keeping at room temp. for	
		48±4 hrs.	